

# Infrared Emitting Diodes(GaAs)

KODENSHI

## KET511

The KET511 is a GaAs IRED mounted in a low profile clear epoxy package. This IRED is both compact and easy to mount.

### FEATURES

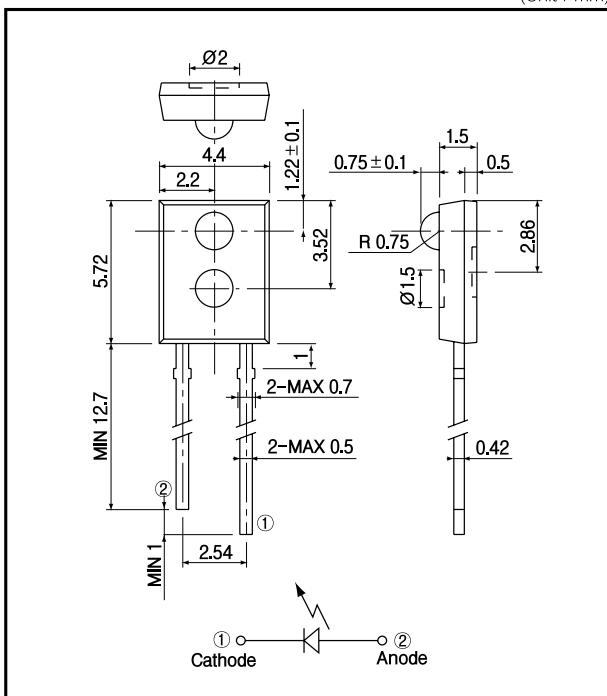
- Plastic mold package

### APPLICATIONS

- Photointerrupters
- Mouses
- Encoders

### DIMENSIONS

(Unit : mm)



### MAXIMUM RATINGS

(Ta=25°C)

Item	Symbol	Rating	Unit
Reverse voltage	V <sub>R</sub>	5	V
Forward current	I <sub>F</sub>	50	mA
Power dissipation	P <sub>D</sub>	75	mW
Pulse forward current <sup>*1</sup>	I <sub>FP</sub>	1	A
Operating temp.	T <sub>opr.</sub>	-30~+85	°C
Storage temp.	T <sub>stg.</sub>	-25~+85	°C
Soldering temp. <sup>*2</sup>	T <sub>sol.</sub>	260	°C

\*1. pulse width : tw ≤ 100 μ sec. period : T = 10msec.

\*2. For MAX.5 seconds at the position of 2 mm from the package

### ELECTRO-OPTICAL CHARACTERISTICS

(Ta=25°C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =20mA		1.2	15	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =5V			10	μA
Peak emission wavelength	λ <sub>p</sub>	I <sub>F</sub> =20mA		940		nm
Spectral bandwidth	Δ λ	I <sub>F</sub> =20mA		50		nm
Radiant intensity <sup>*3</sup>	P <sub>o</sub>	I <sub>F</sub> =4mA		—		mW/sr
Half angle	Δ θ			±40		deg.

\*3. Measured by tester of KODENSHI CORP.

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